



20V N-Channel Enhancement Mode MOSFET

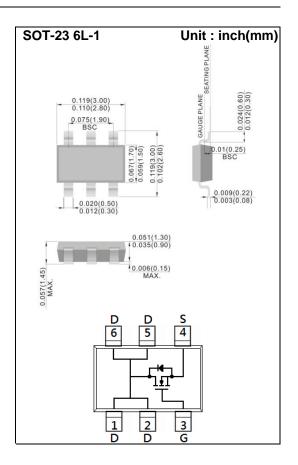
Voltage 20 V Current 7.4A

Features

- RDS(ON), VGS@4.5V, ID@7.4A<27m Ω
- RDS(ON), VGS@2.5V, ID@4.7A<41mΩ
- RDS(ON) , VGS@1.8V, ID@1.8A<85mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc..
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

Mechanical Data

- Case: SOT-23 6L-1 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0005 ounces, 0.014 grams
- Marking: S16



Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	20	V
Gate-Source Voltage		V_{GS}	<u>+</u> 12	V
Continuous Drain Current		I _D	7.4	Α
Pulsed Drain Current		I _{DM}	29.6	Α
Power Dissipation	T _a =25°C	P _D	2	W
	Derate above 25°C		16	mW/°C
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	°C
Typical Thermal resistance				
- Junction to Ambient (Note 3)		$R_{\theta JA}$	62.5	°C/W





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV_{DSS}	V _{GS} =0V, I _D =250uA	20	-	ı	V	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250uA$	0.5	0.77	1.2	V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =4.5V, I _D =7.4A	-	24	27	mΩ	
		V_{GS} =2.5V, I_{D} =4.7A	-	33	41		
		V _{GS} =1.8V, I _D =1.8A	-	62	85		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =20V, V _{GS} =0V	-	0.01	1	uA	
Gate-Source Leakage Current	I_{GSS}	V _{GS} = <u>+</u> 12V, V _{DS} =0V	-	<u>+</u> 10	<u>+</u> 100	nA	
Dynamic							
Total Gate Charge	Q_g	V _{DS} =10V, I _D =7.4A, V _{GS} =4.5V ^(Note 1,2)	-	6.8	1	nC	
Gate-Source Charge	Q_gs		-	1.3	-		
Gate-Drain Charge	Q_gd		-	2	-		
Input Capacitance	Ciss	V _{DS} =10V, V _{GS} =0V, f=1.0MHZ	-	513	-	pF	
Output Capacitance	Coss		-	74	-		
Reverse Transfer Capacitance	Crss		-	60	-		
Switching							
Turn-On Delay Time	td _(on)	V_{DD} =10V, I_{D} =7.4A, V_{GS} =4.5V, R_{G} =6 Ω (Note 1,2)	-	7	-	ns	
Turn-On Rise Time	tr		-	57	-		
Turn-Off Delay Time	td _(off)		-	24	-		
Turn-Off Fall Time	tf		-	14	-		
Drain-Source Diode							
Maximum Continuous Drain-Source Diode Forward Current	Is		-	-	2.0	А	
Diode Forward Voltage	V _{SD}	I _S =1.0A, V _{GS} =0V	-	0.69	1.2	V	

NOTES:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited





TYPICAL CHARACTERISTIC CURVES

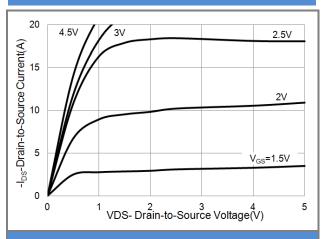


Fig.1 On-Region Characteristics

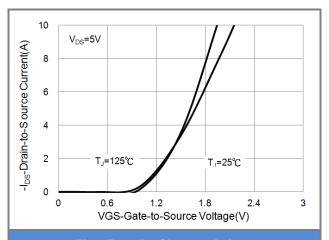


Fig.2 Transfer Characteristics

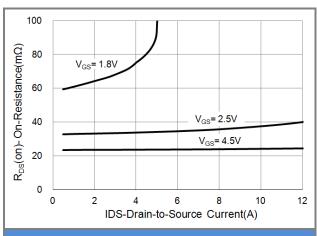


Fig.3 On-Resistance vs. Drain Current

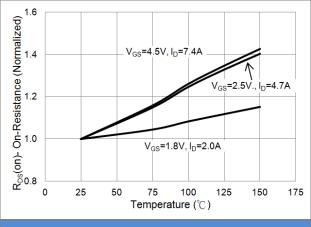


Fig.4 On-Resistance vs. Junction temperature

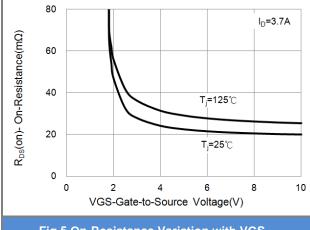
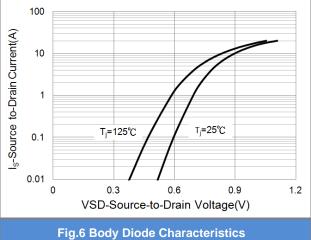


Fig.5 On-Resistance Variation with VGS.







TYPICAL CHARACTERISTIC CURVES

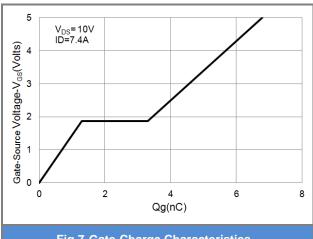


Fig.7 Gate-Charge Characteristics

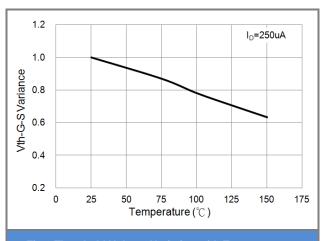


Fig.8 Threshold Voltage Variation with Temperature.

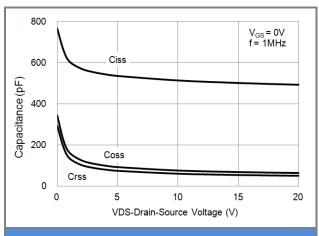


Fig.9 Capacitance vs. Drain-Source Voltage.

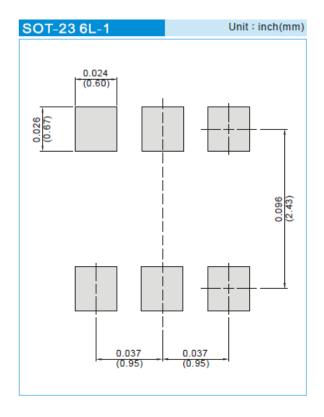




PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJS6416_S1_00001	SOT-23 6L-1	3K pcs / 7" reel	S16	Halogen free

MOUNTING PAD LAYOUT







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